# **ESD Protection Diode**

### **Dual Common Anode**

These dual monolithic silicon ESD protection diodes are intended for use in voltage– and ESD–sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common anode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

#### **Specification Features:**

- SC-89 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model
- Meets IEC61000-4-2 Level 4
- Low Leakage < 5.0 μA
- These are Pb-Free Devices

#### **Mechanical Characteristics:**

CASE: Void-free, Transfer-molded, Thermosetting Plastic

Epoxy Meets UL 94, V-0

**LEAD FINISH:** 100% Matte Sn (Tin)

**MOUNTING POSITION:** Any

**QUALIFIED MAX REFLOW TEMPERATURE:** 

260°C Device Meets MSL 1 Requirements

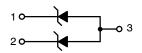


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PIN 1. CATHODE

2. CATHODE 3. ANODE





SC-89 CASE 463C STYLE 4



**MARKING** 

L = Device Code x = Specific Device M = Date Code ■ Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NZL5V6AXV3T1	SC-89*	3000/Tape & Reel
NZL5V6AXV3T1G	SC-89*	3000/Tape & Reel
NZL6V8AXV3T1	SC-89*	3000/Tape & Reel
NZL6V8AXV3T1G	SC-89*	3000/Tape & Reel
NZL6V8AXV3T3G	SC-89*	10000/Tape & Reel
NZL7V5AXV3T1	SC-89*	3000/Tape & Reel
NZL7V5AXV3T1G	SC-89*	3000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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#### **DEVICE MARKING INFORMATION**

See specific marking information in the device marking column of the table on page 2 of this data sheet.

<sup>\*</sup>This package is inherently Pb-Free.

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Total Power Dissipation on FR–5 Board (Note 1) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	240 1.9	mW mW/°C
Thermal Resistance Junction to Ambient	$R_{ hetaJA}$	525	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	T <sub>L</sub>	260	°C
IEC61000-4-2 (Contact)		10	kV

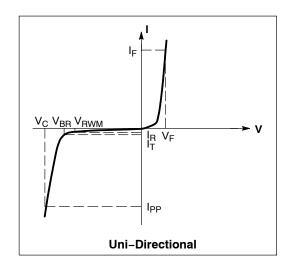
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter
V <sub>RWM</sub>	Working Peak Reverse Voltage
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>
I <sub>T</sub>	Test Current
I <sub>F</sub>	Forward Current
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>



**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$  unless otherwise noted,  $V_F = 0.9$  V Max @  $I_F = 10$  mA for all types) **UNIDIRECTIONAL** (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

				Breakdown Voltage			Surge				
	Device	V <sub>RWM</sub>	I <sub>R</sub> @ V <sub>RWM</sub>	V <sub>BF</sub>	(Note 2)	(V)	@ lz <sub>T</sub>	V <sub>C</sub> (V) @ I <sub>PP</sub> = 1.0 A <sup>†</sup>	V <sub>C</sub> (V) @ Max I <sub>PP</sub> <sup>†</sup>	Мах І <sub>рр</sub> (А) <sup>†</sup>	P <sub>pk</sub> (W) <sup>†</sup>
Device	Marking	V	μΑ	Min	Nom	Max	mA	Тур	Max		Тур
NZL5V6AXV3T1	L0	3.0	5.0	5.32	5.6	5.88	5.0	7.0	10.1	4.8	50
NZL6V8AXV3T1	L2	4.5	1.0	6.46	6.8	7.14	5.0	7.9	11.9	6.7	73
NZL6V8AXV3T3	L2	4.5	1.0	6.46	6.8	7.14	5.0	7.9	11.9	6.7	73
NZL7V5AXV3T1	L3	5.0	1.0	7.12	7.5	7.88	5.0	8.8	13.5	5.7	75

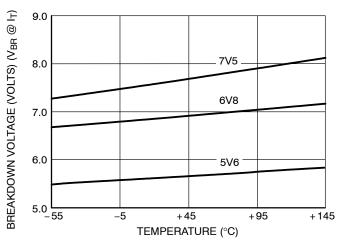
<sup>2.</sup> V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

<sup>1.</sup> FR-5 board with minimum recommended mounting pad.

<sup>\*</sup>Other voltages may be available upon request.

<sup>†</sup> Surge current waveform per Figure 5.

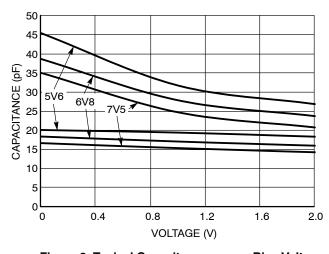
### **TYPICAL CHARACTERISTICS**



250 200 200 150 50 50 0 -55 -5 +45 +95 +145 TEMPERATURE (°C)

Figure 1. Typical Breakdown Voltage versus Temperature

Figure 2. Typical Leakage Current versus Temperature



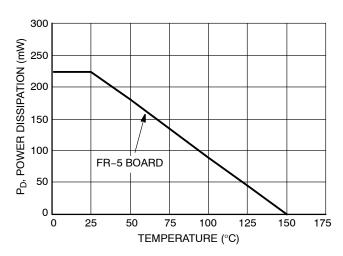


Figure 3. Typical Capacitance versus Bias Voltage (Upper curve for each part is unidirectional mode, lower curve is bidirectional mode)

Figure 4. Steady State Power Derating Curve

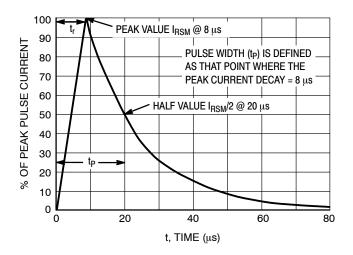
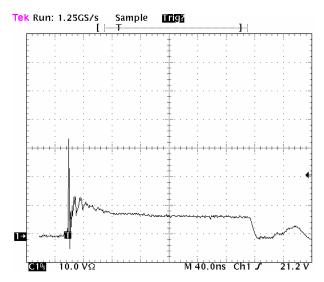
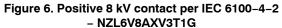


Figure 5. 8 x 20 μs Pulse Waveform





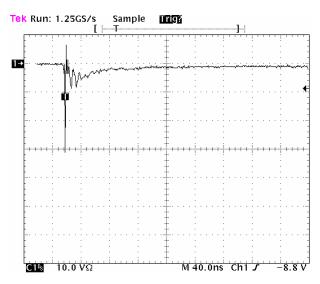


Figure 7. Negative 8 kV contact per IEC 6100-4-2
- NZL6V8AXV3T1G

### TYPICAL COMMON ANODE APPLICATIONS

A dual junction common anode design in an SC-89 package protects two separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. Two simplified examples of surge protection applications are illustrated below.

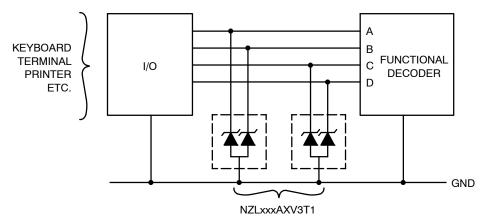


Figure 8. Computer Interface Protection

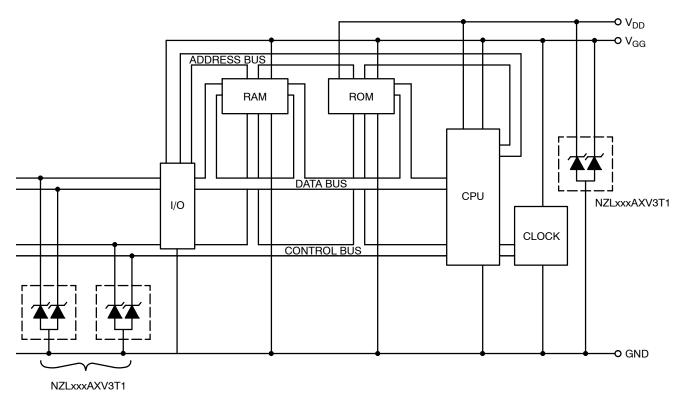
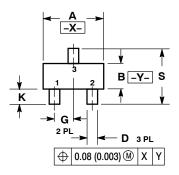
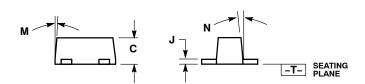


Figure 9. Microprocessor Protection

#### PACKAGE DIMENSIONS

SC-89, 3-LEAD CASE 463C-03 **ISSUE C** 





#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE
- 463C-01 OBSOLETE, NEW STANDARD 463C-02.

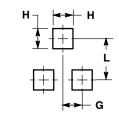
	MIL	LIMETE	ERS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.50	1.60	1.70	0.059	0.063	0.067	
В	0.75	0.85	0.95	0.030	0.034	0.040	
С	0.60	0.70	0.80	0.024	0.028	0.031	
D	0.23	0.28	0.33	0.009	0.011	0.013	
G	C	.50 BSC		0.020 BSC			
Н	C	).53 REF	=	0.021 REF			
J	0.10	0.15	0.20	0.004	0.006	0.008	
K	0.30	0.40	0.50	0.012	0.016	0.020	
L	1	.10 REF	=	0.043 REF			
M			10			10	
N			10 -			10	
S	1.50	1.60	1.70	0.059	0.063	0.067	

STYLE 4:

PIN 1. CATHODE 2. CATHODE

3. ANODE

#### **SOLDERING FOOTPRINT**



RECOMMENDED PATTERN OF SOLDER PADS

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